Spin orbital reorientation transitions induced by magnetic field

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Motivation: SRT like effect



Here we report on a new effect similar to the spin reorientation transition (SRT) that takes place at two magnetic fields of B_{SORT1} and B_{SORT2} .

The effect is observed in the magnetization curves of small Mn³⁺ magnetic clusters in the wurtzite GaN (being in a paramagnetic state) calculated using crystal field model approach.

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The observed effect arises from the interplay of the crystalline environment and the spin–orbit coupling λ SL, therefore we name it spin orbital reorientation transition (SORT)

The value of B_{SORT1} depends on the crystal field model parameters and the number of ions N in a given cluster, whereas B_{SORT2} is controlled mostly by the magnitude of the spin-orbit coupling λ .

The explanation of SORT is given in terms of the spin M_s and orbital momentum M_1 contributions to the total magnetization $M = M_s + M_L$.

Dilute magnetic semiconductor





Ga

С

N

Ga

First spin orbital reorientation transition





(Ga,Mn)N

Crystal field model

Crystal field model for Mn³⁺ ion in GaN: spin and orbital momentum S = 2 and L = 2, respectively





The spin M_s (a) and orbital momentum M_L (b) contributions (per one ion) to the total magnetization $M = M_s + M_L$.

Second spin orbital reorientation transition



Eigenfunctions and eigenvalues are obtained by a numerical diagonalization of the full (25 \times 25), $(25^2 \times 25^2)$, $(25^3 \times 25^3)$, $(25^4 \times 25^4)$ Hamiltonian matrix, for a single ion, pair, triplet or quartet, respectively.

Red and green arrows denote the magnetizations M_S , M_I and M = $M_{\rm S}$ + $M_{\rm I}$ calculated for the magnetic field applied perpendicular and parallel to the **c** axis of GaN respectively. (a) The magnetic anisotropy (MA) is controlled by the dominant spin component M_s. Antiparallel alignment of M_s and M_L is due to the presence of spinorbit interaction λLS with $\lambda > 0$. (b) and (c) In the spin saturation regime with $M_{S,\perp} = M_{S,\parallel} = 4 \ \mu B$ per ion, MA depends on values of the orbital contribution M_L to the total magnetization M. (c) A very strong magnetic field B overcomes the influence of the spin-orbit interaction what results in the reversal of M₁ and the occurrence of

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